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Case No. 9905/28 Client No. BIF023237/US

UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)	
FOURNEL et al.)	
Serial No.: Not Yet Assigned)	Examiner: Not Yet Assigned
Filing Date: Herewith)	Group Art Unit:
For: METHOD FOR MAKING A STRESSED STRUCTURE DESIGNED TO BE DISSOCIATED)	Not Yet Assigned

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450

Alexandria, Virginia 22313-1450

Dear Sir:

In accordance with the duty of disclosure under 37 C.F.R. §1.56 and §§1.97-1.98, and more particularly in accordance with 37 C.F.R. §1.97(b), Applicants hereby cite the following references:

No.	Date of Publication	Patentee/Applicant/Country	
5,400,458	03/28/1995	Huber et al.	
4,254,590	03/10/1981	Eisele et al.	
5,374,564,	12/20/1994	Bruel	
FR 2 681 472 A1	03/19/1993	France	
WO 00/48238	08/17/2000	PCT	
EP 1 050 901 A2	11/08/2000	EPO	
ED 0 410 670 A1	07/24/1000	EDO	

Feijoo et al., "Prestressing of Bonded Wafers", Proceedings of the 1st International Symposium on Semiconductor Wafer Bonding, Science Technology and Applications, Vol. 92-7, The Electrochemical Society (1992), pp. 230-238.

07/05/1999

Feiioo et al.. "Generalized Formula for Curvature Radius and Layer Stresses Caused by Thermal Strain in Semiconductor Multilayer Structures," Appl. Phys. 54(1), 1983, page 83. S. Timoshenko, "Analysis of Bi-Metal Thermostats," J. Opt. Soc. Am. 11 (1925), page 233-256.

Japan

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FORM PTO-1449	SERIAL NO. Not Yet Assigned	(BIF023237/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE GF	ROUP ART UNIT Not Yet Assigned
	APPLICANTS: FOURNEL et al.	

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER Number-Kind Code (if known)	DATE	NAME	CLASS/ SUBCLASS	FILING DATE
	A1	5,400,458	03/28/1995	Huber et al.		
	A2	4,254,590	03/10/1981	Eisele et al.		
	A3	5,374,564	12/20/1994	Bruel		

FOREIGN PATENT DOCUMENT

EXAMINER INITIAL		DOCUMENT NUMBER Number-Kind Code (if known)	DATE	COUNTRY	CLASS/ SUBCLAS S	TRANSLATION YES OR NO
	A4	FR 2 681 472 A1	03/19/1993	France		
	A5	WO 00/48238	08/17/2000	PCT		
	A6	EP 1 050 901 A2	11/08/2000	EPO		
	A7	EP 0 410 679 A1	07/24/1990	EPO		
	A8	101004013	07/05/1999	Japan		Abstract only

EXAMINER	OTHER ART – NON PATENT LITERATURE DOCUMENTS					
INITIAL		(Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial,				
	syn	posium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.				
	A9					
		Symposium on Semiconductor Wafer Bonding, Science Technology and Applications,				
		Vol. 92-7, The Electrochemical Society (1992), pp. 230-238.				
	A10	Feijoo et al., "Generalized Formula for Curvature Radius and Layer Stresses Caused by Thermal Strain in Semiconductor Multilayer Structures," Appl. Phys. 54(1), 1983, page 83.				
	A11	S. Timoshenko, "Analysis of Bi-Metal Thermostats," J. Opt. Soc. Am. 11 (1925), page 233-256.				

EXAMINER	/Elias Ullah/	DATE CONSIDERED	11/20/2008

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.